

# SB5100U

Technical Data Data Sheet N0092, Rev. B RoHS 🗭

SB5100U SCHOTTKY RECTIFIER

# DO-201AD

**Circuit Diagram** 



### Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- "-A" is an AEC-Q101 qualified device
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Disk drivesBattery charging

### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Characteristic	Symbol	SB5100U	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	v
Maximum RMS Voltage	V <sub>RMS</sub>	70	V
Average Rectified Output Current (Note 1) @T <sub>A</sub> =80°C	IF(AV)	5.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	120	A
Forward Voltage $@I_F = 5.0A, T_A = 25^{\circ}C$ $@I_F = 5.0A, T_A = 125^{\circ}C$	V <sub>FM</sub>	0.82 0.67	V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$	I <sub>RM</sub>	0.5 10	mA
Maximum Junction Capacitance (Note 2)	Cj	250	pF
Typical Thermal Resistance Junction to Ambient	R <sub>0JA</sub>	25	K/W
Storage Temperature Range	TJ,TSTG	-55 to +150	°C
Approximate Weight	wt	1.02	g
Case Style		DO-201AD	

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

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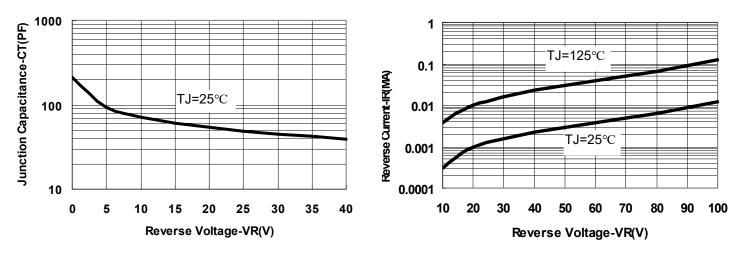
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2. Measured at 1MHz and applied reverse voltage of 5.0V D.C.

### **Ratings and Characteristics Curves**





**Fig.2-Typical Reverse Current** 

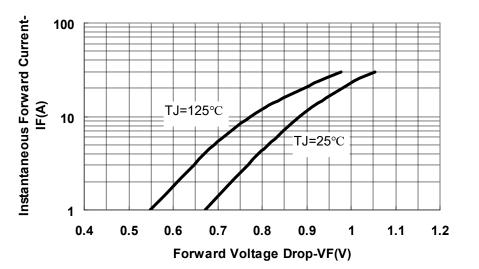


Fig.3-Typical Forward Voltage Drop Characteristics

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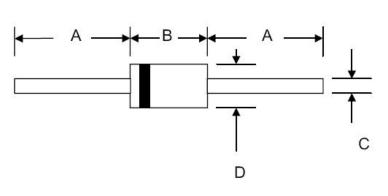


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### **Mechanical Dimensions DO-201AD**



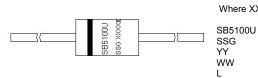
SYMDOL	Millimeters		Inches	
SYMBOL	Min.	Max.	Min.	Max.
А	25.4	-	1.000	-
В	8.50	9.50	0.335	0.374
С	1.2	1.3	0.048	0.052
D	5.0	5.6	0.197	0.220

# **Ordering Information**

Device	Package	Shipping	
SB5100U	DO-201AD	1250noo / tono	
	(Pb-Free)	1250pcs / tape	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

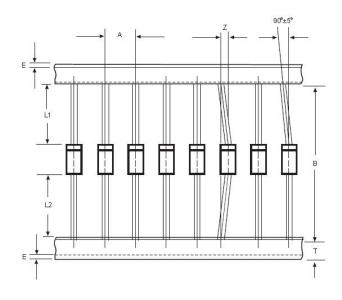
# **Marking Diagram**



Where XXXXX i	is YYWWL
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- = Part Name = SSG
- = Year = Week
- = Lot Number

# **Carrier Tape Specification DO-201AD**



SYMBOL	Millimeters		
STWBUL	Min.	Max.	
А	9.50	10.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
E	-	0.80	
IL1-L2I	-	1.0	



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